



### **60V N-Channel Enhancement Mode MOSFET**

Voltage

60 V

Current

70 A

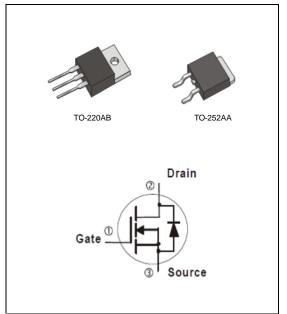
#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ , $I_D@20A<8.5m\Omega$
- High switching speed
- Low Gate Charge
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

#### **Mechanical Data**

• Case: TO-252AA, TO-220AB Package

• Terminals: Solderable per MIL-STD-750, Method 2026



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	TO-252AA	UNITS
Drain-Source Voltage		$V_{DS}$	60		V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 25		V
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	70		A
	T <sub>C</sub> =100°C		44		
Pulsed Drain Current	T <sub>C</sub> =25°C	I <sub>DM</sub>	180		
Power Dissipation	T <sub>C</sub> =25°C	PD	100	83	W
	T <sub>C</sub> =100°C		40	33	
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	101		mJ
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150		°C
Typical Thermal Resistance					
<ul><li>Junction to Case</li><li>Junction to Ambient</li></ul>		R <sub>θJC</sub> R <sub>θJA</sub>	1.25 62.5	1.5 110	°C/W

• Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}=0V,I_{D}=250uA$	60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	2.0	3.0	4.0			
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =20A	-	7	8.5	mΩ		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =48V,V <sub>GS</sub> =0V	-	-	1.0	uA		
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 25V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 7)								
Total Gate Charge	Qg	V <sub>DS</sub> =30V, I <sub>D</sub> =30A, V <sub>GS</sub> =10V <sup>(Note 2,3)</sup>	-	71	-	nC		
Gate-Source Charge	Q <sub>gs</sub>		-	16	-			
Gate-Drain Charge	Q <sub>gd</sub>		-	26	-			
Input Capacitance	Ciss	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	3116	-	pF		
Output Capacitance	Coss	$V_{DS}$ =30V, $V_{GS}$ =0V, $f$ =1.0MHZ	-	317	-			
Reverse Transfer Capacitance	Crss	I=I.UIVIHZ	-	214	-			
Turn-On Delay Time	td <sub>(on)</sub>	.,	-	20	-			
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =30V, $I_{D}$ =30A, $V_{GS}$ =10V, $R_{G}$ =25 $\Omega$	-	100	-			
Turn-Off Delay Time	td <sub>(off)</sub>		-	66	-			
Turn-Off Fall Time	t <sub>f</sub>		-	84	-			
Drain-Source Diode								
Maximum Continuous Drain-Source	,		-	-	70	А		
Diode Forward Current	I <sub>S</sub>							
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	0.8	1.3	V		

#### NOTES:

- 1. Pulse width < 300us, Duty cycle < 2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejua is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- The test condition is L=0.1mH, I<sub>AS</sub>=45A, R<sub>G</sub>=25ohm, Starting T<sub>J</sub>=25°C
- 7. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

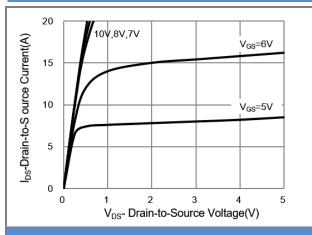


Fig.1 Output Characteristics

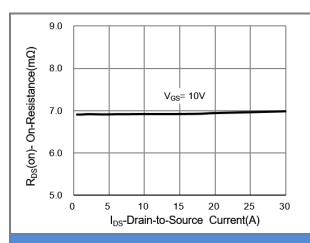
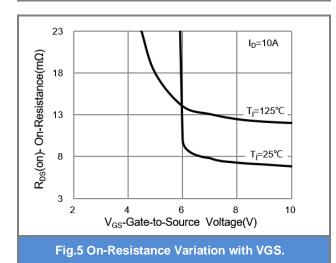
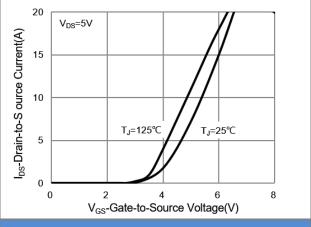


Fig.3 On-Resistance vs. Drain Current





**Fig.2 Transfer Characteristics** 

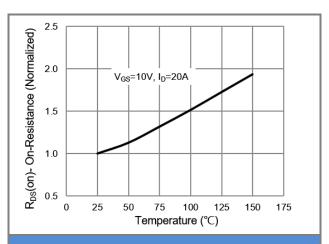


Fig.4 On-Resistance vs. Junction temperature

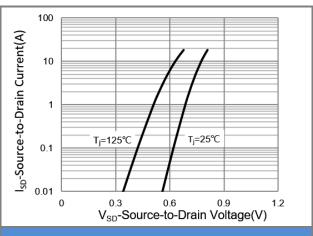


Fig.6 Source-Drain Diode Forward Voltage





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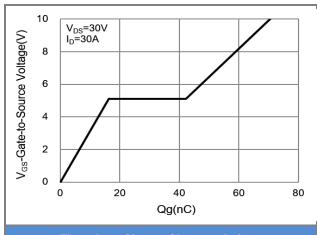


Fig.7 Gate-Charge Characteristics

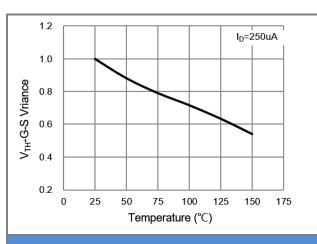
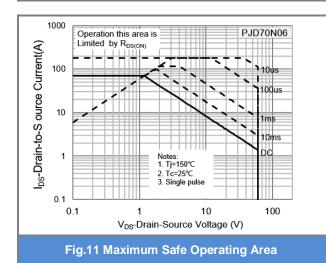


Fig.9 Threshold Voltage Variation with Temperature



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Fig.8 Breakdown Voltage Variation vs. Temperature

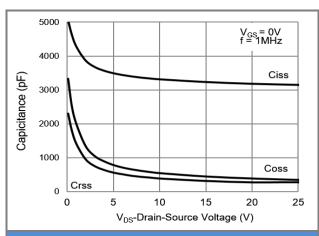


Fig.10 Capacitance vs. Drain-Source Voltage

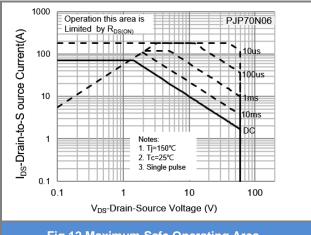


Fig.12 Maximum Safe Operating Area





#### TYPICAL CHARACTERISTIC CURVES

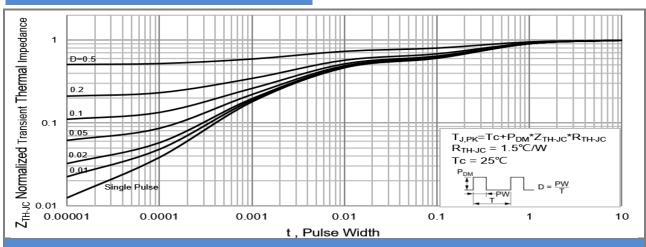


Fig.13 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

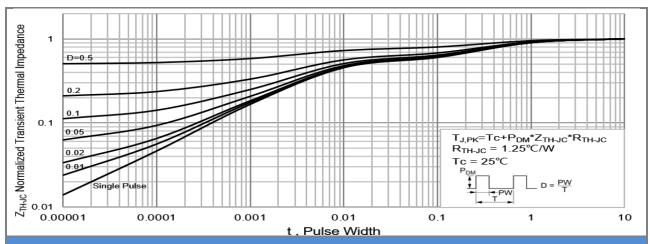
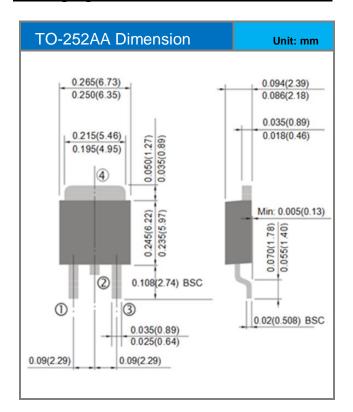


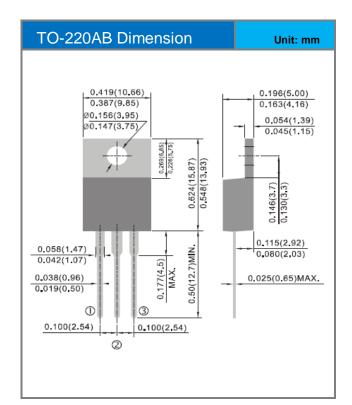
Fig.14 Normalized Transient Thermal Impedance vs. Pulse Width





#### **Packaging Information**





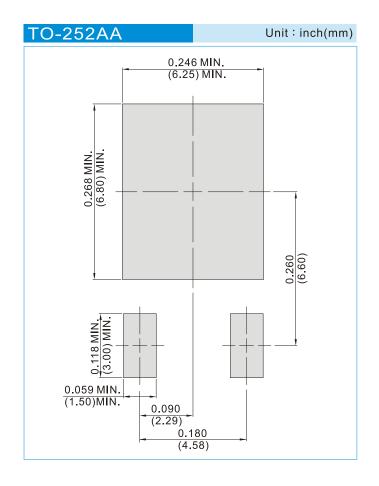




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD70N06_L2_00001	TO-252AA	3,000pcs / 13" reel	D70N06	Halogen free
PJP70N06_T0_00001	TO-220AB	50pcs / Tube	P70N06	Halogen free

### **MOUNTING PAD LAYOUT**



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